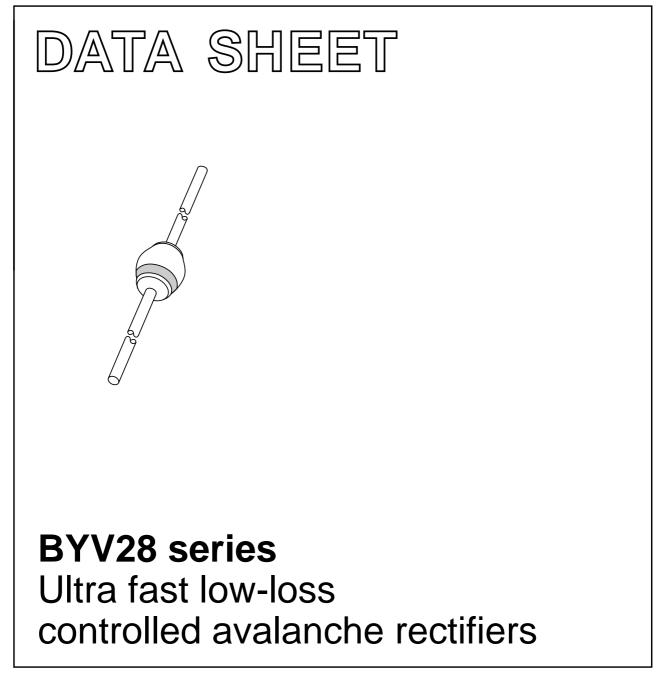
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1996 Oct 02 1997 Nov 24



Philips Semiconductors

Product specification

BYV28 series

Ultra fast low-loss controlled avalanche rectifiers

FEATURES

- · Glass passivated
- High maximum operating temperature
- Low leakage current
- · Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack
- Also available with preformed leads for easy insertion.

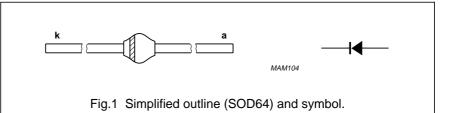
LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|--------------------|---------------------------------|---|------|------|------|
| V _{RRM} | repetitive peak reverse voltage | | | | |
| | BYV28-50 | | _ | 50 | V |
| | BYV28-100 | | _ | 100 | V |
| | BYV28-150 | | _ | 150 | V |
| | BYV28-200 | | _ | 200 | V |
| | BYV28-300 | | _ | 300 | V |
| | BYV28-400 | | _ | 400 | V |
| | BYV28-500 | | _ | 500 | V |
| | BYV28-600 | | _ | 600 | V |
| V _R | continuous reverse voltage | | | | |
| | BYV28-50 | | _ | 50 | V |
| | BYV28-100 | | _ | 100 | V |
| | BYV28-150 | | _ | 150 | V |
| | BYV28-200 | | _ | 200 | V |
| | BYV28-300 | | _ | 300 | V |
| | BYV28-400 | | _ | 400 | V |
| | BYV28-500 | | _ | 500 | V |
| | BYV28-600 | | _ | 600 | V |
| I _{F(AV)} | average forward current | $T_{tp} = 85 \ ^{\circ}C;$ lead length = 10 mm; | | | |
| | BYV28-50 to 400 | see Figs 2 and 3; | _ | 3.5 | A |
| | BYV28-500 and 600 | averaged over any 20 ms period; see also Figs 10 and 11 | _ | 3.1 | А |
| I _{F(AV)} | average forward current | T _{amb} = 60 °C; printed-circuit board | | | |
| | BYV28-50 to 400 | mounting (see Fig.20); | - | 1.9 | A |
| | BYV28-500 and 600 | see Figs 4 and 5; averaged over any 20 ms period; see also Figs 10 and 11 | - | 1.5 | A |

DESCRIPTION

Rugged glass SOD64 package, using a high temperature alloyed construction. This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



BYV28 series

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------------|---|------|------|------|
| I _{FRM} | repetitive peak forward current | $T_{tp} = 85 \text{ °C}$; see Figs 6 and 7 | | | |
| | BYV28-50 to 400 | | _ | 32 | A |
| | BYV28-500 and 600 | | _ | 31 | A |
| I _{FRM} | repetitive peak forward current | T _{amb} = 60 °C; see Figs 8 and 9 | | | |
| | BYV28-50 to 400 | | _ | 17 | A |
| | BYV28-500 and 600 | | _ | 16 | A |
| I _{FSM} | non-repetitive peak forward current | t = 10 ms half sine wave; | _ | 90 | A |
| | | $T_j = T_j \max_{max} prior to surge;$ | | | |
| | | $V_{R} = V_{RRMmax}$ | | | |
| E _{RSM} | non-repetitive peak reverse | L = 120 mH; $T_j = T_{j max}$ prior to | _ | 20 | mJ |
| | avalanche energy | surge; inductive load switched off | | | |
| T _{stg} | storage temperature | | -65 | +175 | °C |
| Tj | junction temperature | see Fig.12 | -65 | +175 | °C |

ELECTRICAL CHARACTERISTICS

 T_j = 25 $^\circ C$ unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------|--|---|------|------|------|------|
| V _F | forward voltage | $I_F = 3.5 \text{ A}; T_j = T_{j \text{ max}};$ | | | | |
| | BYV28-50 to 200 | see Figs 13, 14 and 15 | _ | _ | 0.80 | V |
| | BYV28-300 and 400 | | _ | _ | 0.83 | V |
| | BYV28-500 and 600 | | _ | _ | 0.98 | V |
| V _F | forward voltage | I _F = 3.5 A; | | | | |
| | BYV28-50 to 200 | see Figs 13, 14 and 15 | _ | _ | 1.02 | V |
| | BYV28-300 and 400 | | _ | _ | 1.05 | V |
| | BYV28-500 and 600 | | _ | _ | 1.25 | V |
| V _{(BR)R} | reverse avalanche breakdown voltage | I _R = 0.1 mA | | | | |
| | BYV28-50 | | 55 | _ | _ | V |
| | BYV28-100 | | 110 | _ | _ | V |
| | BYV28-150 | | 165 | _ | _ | V |
| | BYV28-200 | | 220 | _ | _ | V |
| | BYV28-300 | | 330 | _ | _ | V |
| | BYV28-400 | | 440 | _ | _ | V |
| | BYV28-500 | | 560 | _ | _ | V |
| | BYV28-600 | | 675 | - | _ | V |
| I _R | reverse current | V _R = V _{RRMmax} ; see Fig.16 | _ | _ | 5 | μA |
| | | $V_R = V_{RRMmax}$; $T_j = 165 \text{ °C}$; see Fig.16 | _ | _ | 150 | μA |
| t _{rr} | reverse recovery time | when switched from | | | | 1 |
| | BYV28-50 to 200 | $I_F = 0.5 \text{ A to } I_R = 1 \text{ A};$ | _ | - | 25 | ns |
| | BYV28-300 to 600 | measured at I _R = 0.25 A; see Fig.22 | - | - | 50 | ns |

BYV28 series

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|----------------------------------|---|---|------|------|------|------|
| C _d | diode capacitance | $f = 1 MHz; V_R = 0;$ | | | | |
| | BYV28-50 to 200 | see Figs 17, 18 and 19 | _ | 190 | _ | pF |
| | BYV28-300 and 400 | | _ | 150 | _ | pF |
| | BYV28-500 and 600 | | - | 125 | - | pF |
| $\left \frac{dI_R}{dt} \right $ | maximum slope of reverse recovery current | when switched from $I_F = 1 \text{ A to } V_R \ge 30 \text{ V and}$ $dI_F/dt = -1 \text{ A}/\mu \text{s}; \text{ see Fig.21}$ | - | - | 4 | A/μs |

THERMAL CHARACTERISTICS

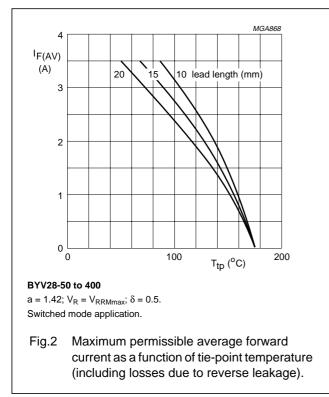
| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|---------------------|-------|------|
| R _{th j-tp} | thermal resistance from junction to tie-point | lead length = 10 mm | 25 | K/W |
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 75 | K/W |

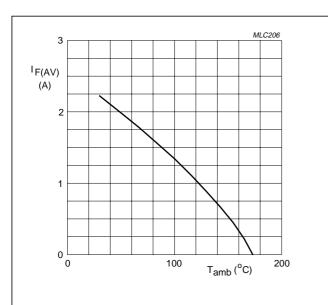
Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer ≥40 μm, see Fig.20 For more information please refer to the *"General Part of associated Handbook"*.

BYV28 series

GRAPHICAL DATA

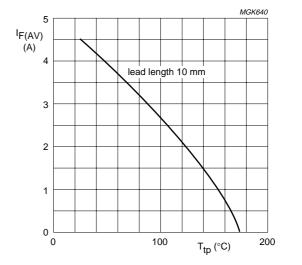




BYV28-50 to 400

a = 1.42; V_R = V_{RRMmax}; δ = 0.5; switched mode application. Device mounted as shown in Fig.20.

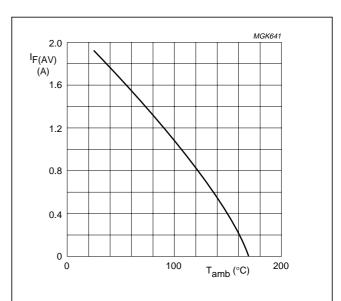
Fig.4 Maximum permissible average forward current as a function of ambient temperature (including losses due to reverse leakage).



BYV28-500 and 600

a = 1.42; $V_R = V_{RRMmax}$; $\delta = 0.5$. Switched mode application.

Fig.3 Maximum permissible average forward current as a function of tie-point temperature (including losses due to reverse leakage).

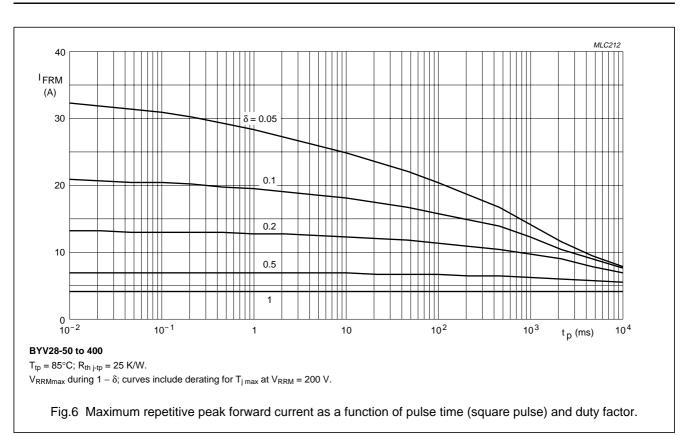


BYV28-500 and 600

a = 1.42; V_R = V_{RRMmax}; \delta = 0.5; switched mode application. Device mounted as shown in Fig.20.

Fig.5 Maximum permissible average forward current as a function of ambient temperature (including losses due to reverse leakage).

BYV28 series



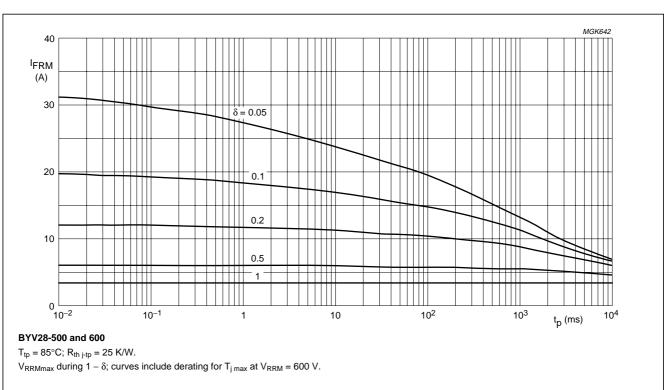
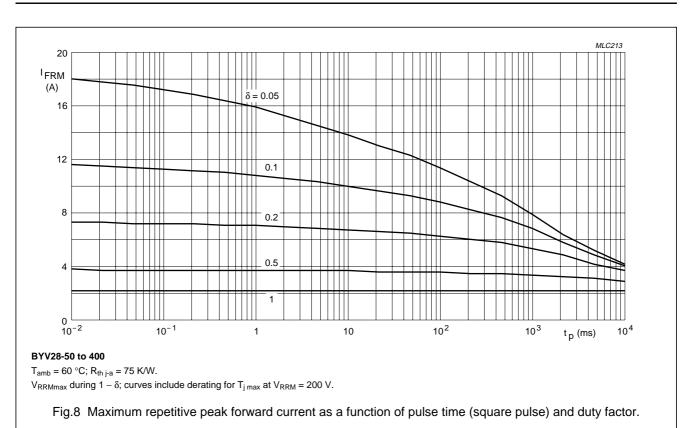
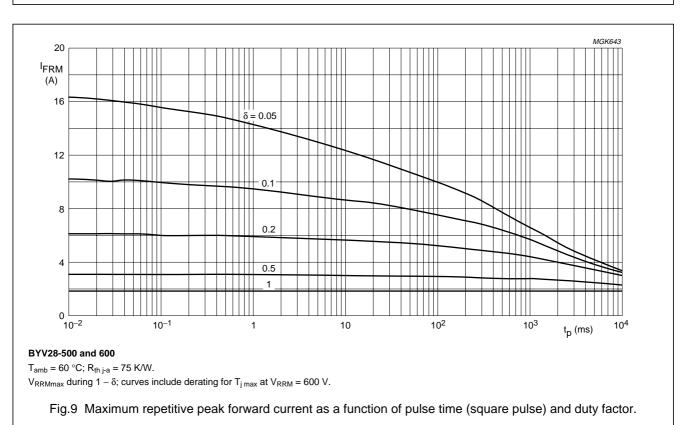


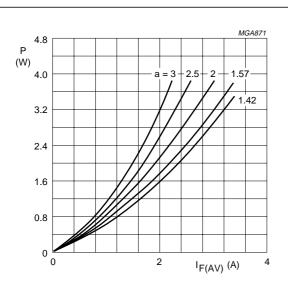
Fig.7 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.

BYV28 series





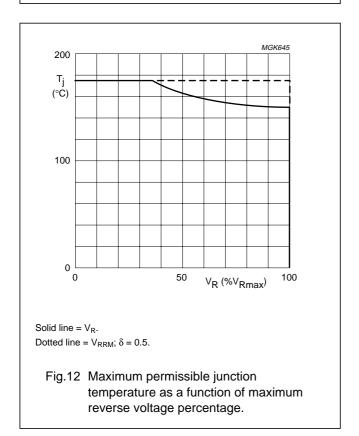
BYV28 series



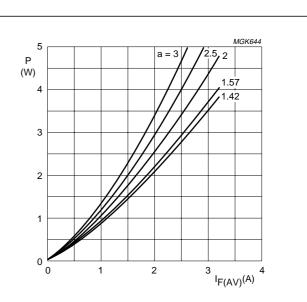
BYV28-50 to 400

 $a = I_{F(RMS)}/I_{F(AV)}; V_R = V_{RRMmax}; \delta = 0.5.$

Fig.10 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.



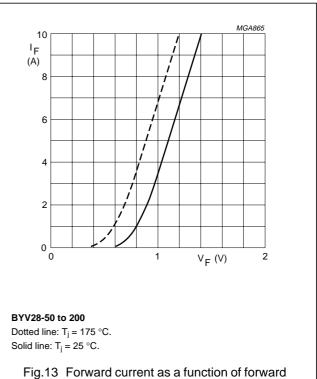
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BYV28-500 and 600

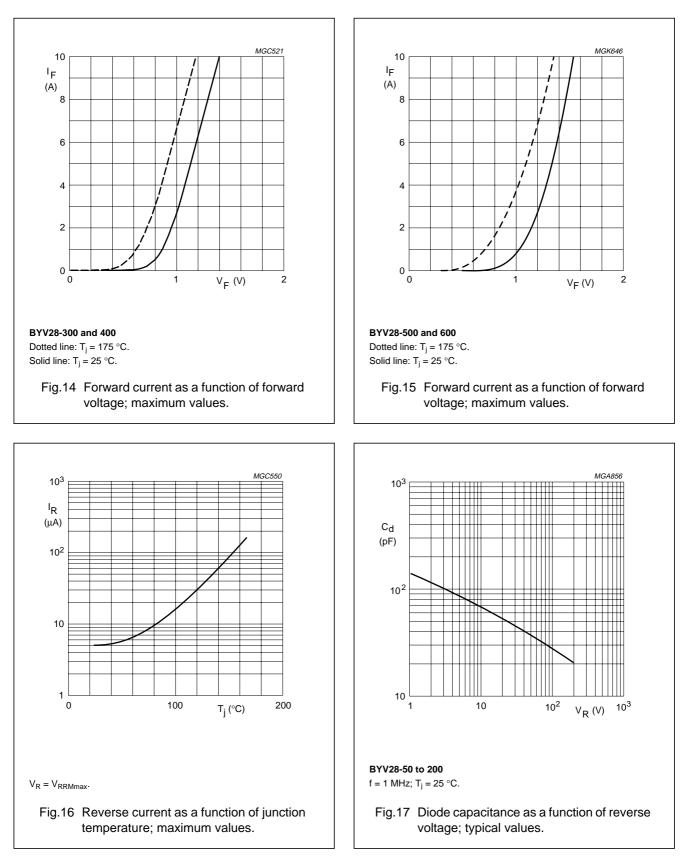
 $a = I_{F(RMS)}/I_{F(AV)}; V_R = V_{RRMmax}; \delta = 0.5.$

Fig.11 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.



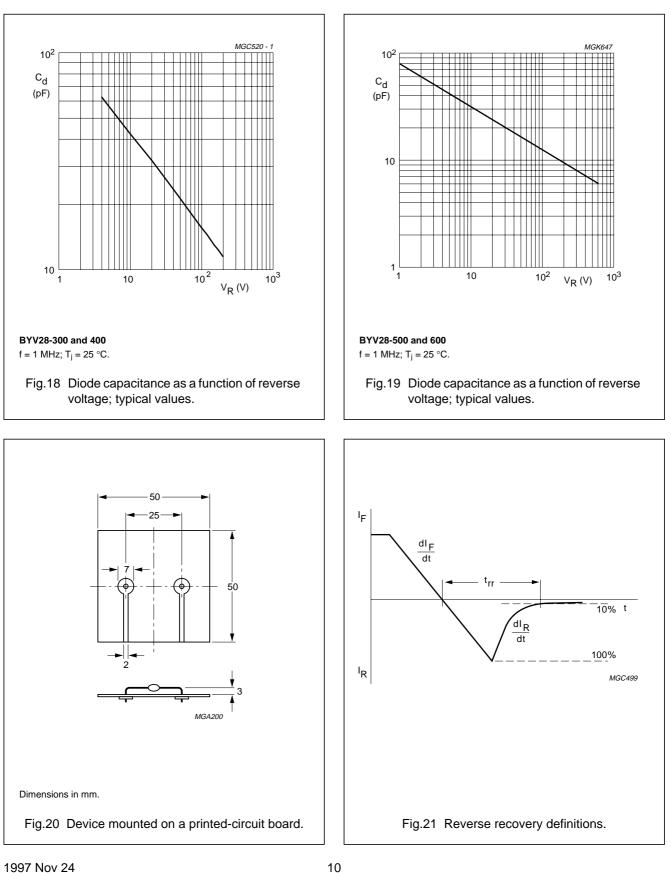
voltage; maximum values.

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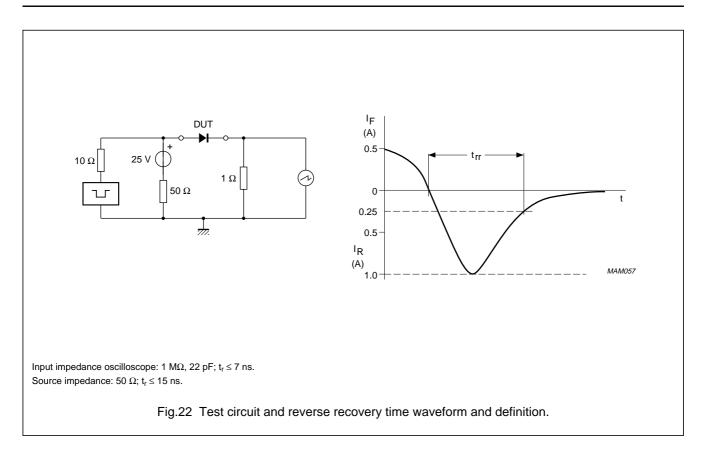


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BYV28 series



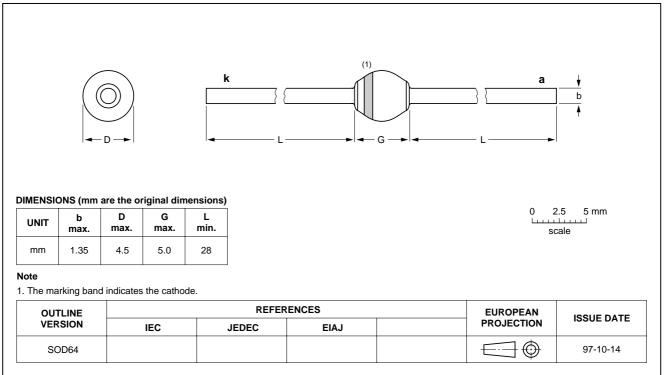
BYV28 series



Ultra fast low-loss controlled avalanche rectifiers

PACKAGE OUTLINE

Hermetically sealed glass package; axial leaded; 2 leads



DEFINITIONS

| Data Sheet Status | | |
|---|---|--|
| Objective specification | This data sheet contains target or goal specifications for product development. | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. | |
| Product specification | This data sheet contains final product specifications. | |
| Limiting values | | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | | |
| Application information | | |

Where application information is given, it is advisory and does not form part of the specification.

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1997 Nov 24

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